

YG868C12R (30A)

(120V / 30A)

[0401]

High Voltage Schottky barrier diode

■ Major characteristics

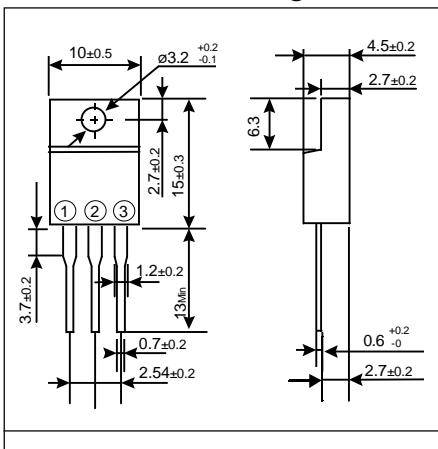
Characteristics	YG868C12R	Units	Condition
V _{RRM}	120	V	
V _F	0.88	V	T _c =25°C MAX.
I _O	30	A	

■ Features

- Low V_F
- High Voltage
- Center tap connection
- High frequency operation
- DC-DC converters
- AC adapter

■ Applications

■ Outline drawings, mm



Package : TO-220F
Epoxy resin UL : V-0

■ Maximum ratings and characteristics

- Absolute maximum ratings (at T_c=25°C Unless otherwise specified)

Item	Symbol	Conditions	Rating	Unit
Repetitive peak surge reverse voltage	V _{RSM}	t _w =500ns, duty=1/40	120	V
Repetitive peak reverse voltage	V _{RRM}		120	V
Isolating voltage	V _{iso}	Terminals-to-Case, AC.1min	1500	V
Average output current	I _O	Square wave, duty=1/2 T _c =115°C	30 *	A
Non-repetitive surge current **	I _{FSM}	Sine wave 10ms 1shot	225	A
Operating junction temperature	T _j		+150	°C
Storage temperature	T _{stg}		-40 to +150	°C

* Out put current of center tap full wave connection

**Rating per element

- Electrical characteristics (at T_c=25°C Unless otherwise specified)

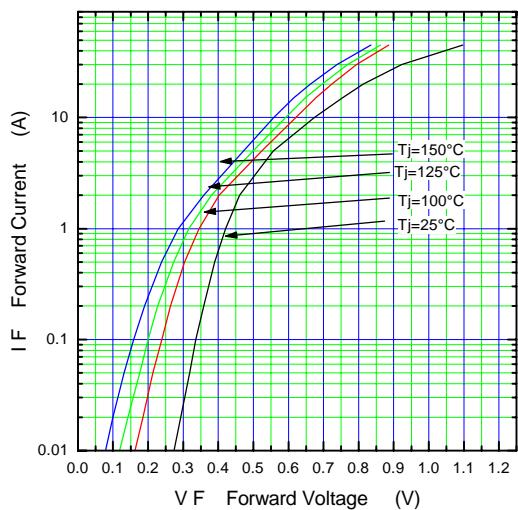
Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V _F	I _{FM} =15A	0.88	V
Reverse current	I _R	V _R =V _{RRM}	200	μA
Thermal resistance	R _{th(j-c)}	Junction to case	1.2	°C/W

- Mechanical characteristics

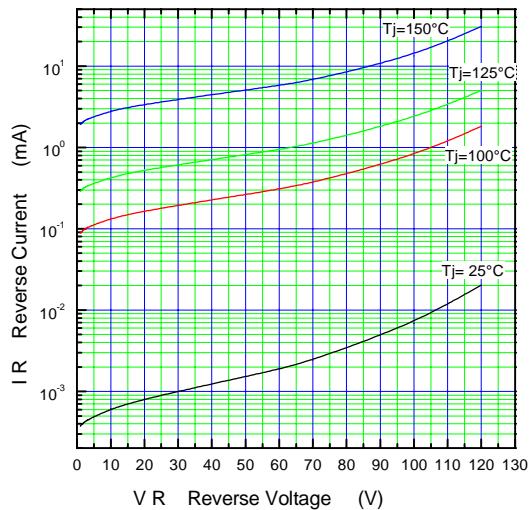
Mounting torque	Recommended torque	0.3 to 0.5	N·m
Approximate mass		2	g

■ Characteristics

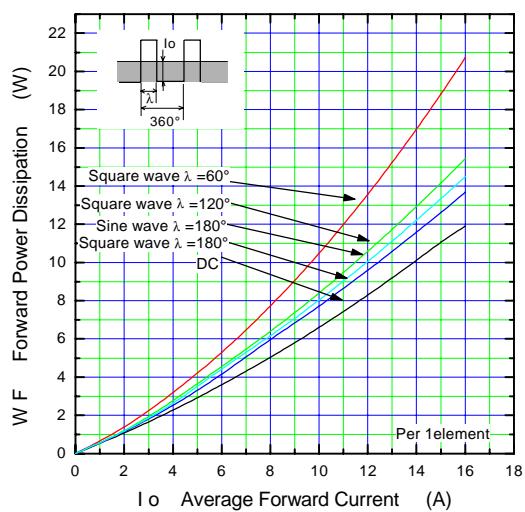
Forward Characteristic (typ.)



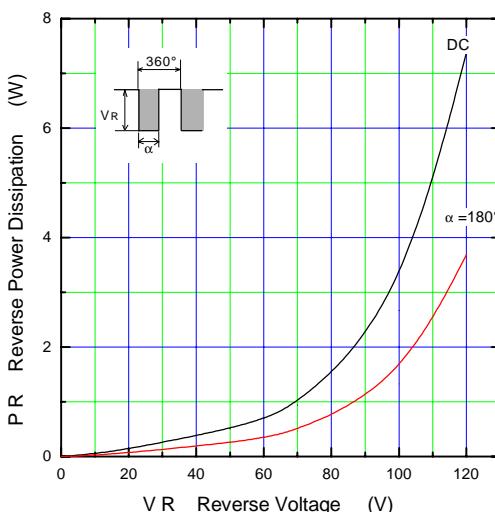
Reverse Characteristic (typ.)



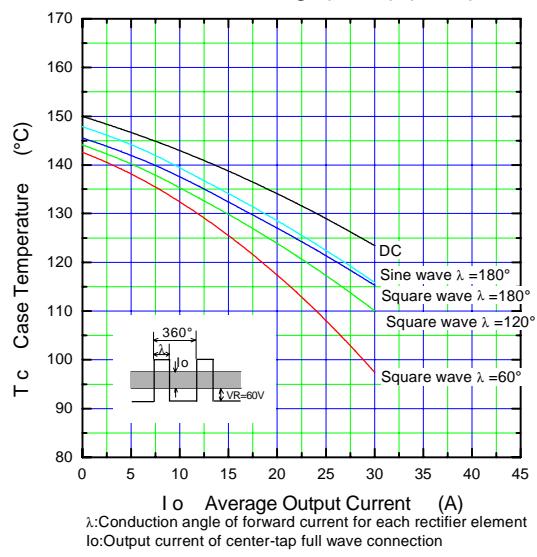
Forward Power Dissipation (max.)



Reverse Power Dissipation (max.)



Current Derating (I_o-T_c) (max.)



λ :Conduction angle of forward current for each rectifier element
 I_o :Output current of center-tap full wave connection

Junction Capacitance Characteristic (max.)

